

**TOSHIBA**

**TCD1501C**

TENTATIVE TOSHIBA CCD LINEAR IMAGE SENSOR CCD(Charge Coupled Device)

# TCD1501C

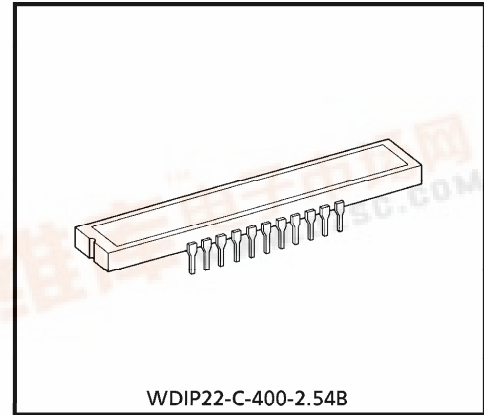
The TCD1501C which includes sample-and-hold circuit is a high sensitive and low dark current 5000 elements CCD image sensor.

The sensor is designed for facsimile, imagescanner and OCR.

The device contains a row of 5000 elements photodiodes which provide a 16 lines / mm (400DPI) across a A3 size paper. The device is operated by 5V (pulse), and 12V power supply.

**FEATURES**

- Number of Image Sensing Elements : 5000 elements
- Image Sensing Element Size :  $7\mu\text{m}$  by  $7\mu\text{m}$  on  $7\mu\text{m}$  centers
- Photo Sensing Region : High sensitive and low voltage dark signal pn photodiode
- Clock : 2 Phase (5V)
- Internal Circuit : S/H circuit
- Package : 22pin DIP



WDIP22-C-400-2.54B

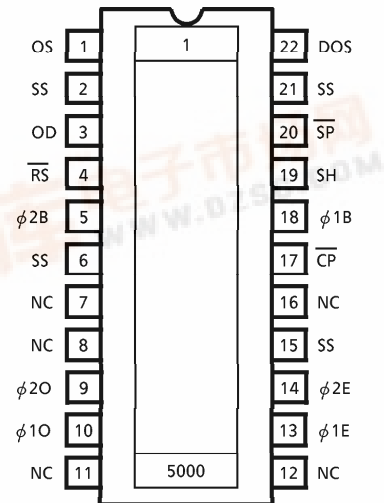
Weight : 5.4g (Typ.)

**MAXIMUM RATINGS (Note 1)**

CHARACTERISTIC	SYMBOL	RATING	UNIT
Clock Pulse Voltage	$V_{\phi}$	- 0.3~8	V
Shift Pulse Voltage	$V_{SH}$		
Reset Pulse Voltage	$V_{RS}$		
Clamp Pulse Voltage	$V_{CP}$		
Sample and Hold Pulse Voltage	$V_{SP}$		
Power Supply Voltage	$V_{OD}$	- 0.3~15	
Operating Temperature	$T_{opr}$	- 25~60	°C
Storage Temperature	$T_{stg}$	- 40~100	°C

(Note 1) All voltage are with respect to SS terminals (Ground).

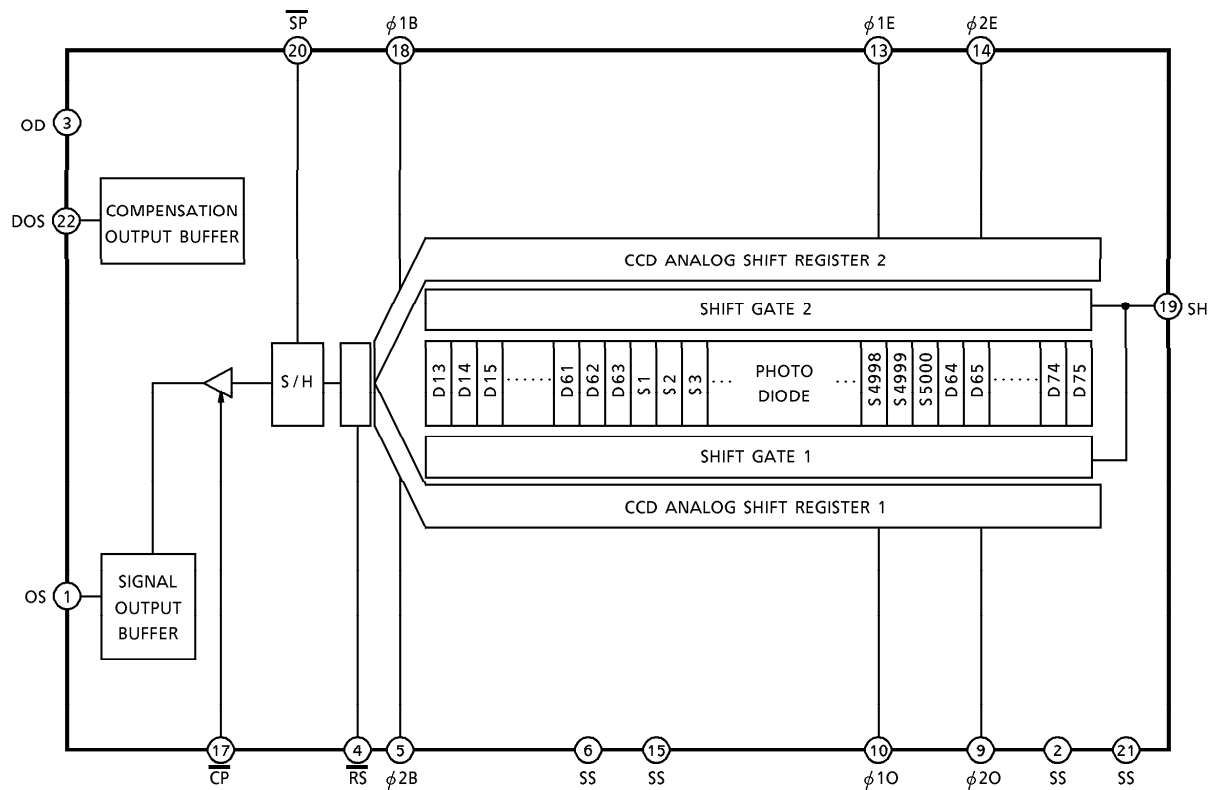
**PIN CONNECTIONS**



(TOP VIEW)

961001EBA2

**CIRCUIT DIAGRAM**



**PIN NAME**

$\phi 1E, O$	Clock (Phase 1)
$\phi 2E, O$	Clock (Phase 2)
$\phi 1B$	Final Stage Clock (Phase 1)
$\phi 2B$	Final Stage Clock (Phase 2)
SH	Shift Gate
$\overline{RS}$	Reset Gate
$\overline{SP}$	Sample and Hold Gate
$\overline{CP}$	Clamp Gate
OS	Signal Output
DOS	Compensation Output
OD	Power
SS	Ground
NC	Non Connection

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**OPTICAL / ELECTRICAL CHARACTERISTICS**

(Ta = 25°C, V<sub>OD</sub> = 12V, V<sub>φ</sub> = V<sub>RS</sub> = V<sub>SH</sub> = V<sub>SP</sub> = V<sub>CP</sub> = 5V, f<sub>φ</sub> = 0.5MHz, f<sub>RS</sub> = 1MHz, t<sub>INT</sub> (INTEGRATION TIME) = 10ms, LIGHT SOURCE = DAYLIGHT FLUORESCENT LAMP, LOAD RESISTANCE = 100kΩ)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	NOTE
Sensitivity	R	10.4	13	15.6	V / lx·s	
Photo Response Non Uniformity	PRNU	—	—	10	%	(Note 2)
	PRNU (3)	—	6	10	mV	(Note 9)
Register Imbalance	RI	—	—	3	%	(Note 3)
Saturation Output Voltage	V <sub>SAT</sub>	2	3	—	V	(Note 4)
Saturation Exposure	SE	0.13	0.23	—	lx·s	(Note 5)
Dark Signal Voltage	V <sub>DRK</sub>	—	1	2	mV	(Note 6)
Dark Signal Non Uniformity	DSNU	—	2	3	mV	(Note 6)
DC Power Dissipation	P <sub>D</sub>	—	240	325	mW	
Total Transfer Efficiency	TTE	92	—	—	%	
Output Impedance	Z <sub>O</sub>	—	0.5	1	kΩ	
Dynamic Range	DR	—	3000	—	—	(Note 7)
DC Signal Output Voltage	V <sub>OS</sub>	4	5	6.5	V	(Note 8)
DC Compensation Output Voltage	V <sub>DOS</sub>	4	5	6.5	V	(Note 8)
DC Differential Error Voltage	V <sub>OS</sub> - V <sub>DOS</sub>	—	—	400	mV	

(Note 2) Measured at 50% of SE (Typ.)

$$\text{Definition of PRNU : PRNU} = \frac{\Delta\bar{x}}{\bar{x}} \times 100 (\%)$$

Where  $\bar{x}$  is average of total signal output and  $\Delta\bar{x}$  is the maximum deviation from  $\bar{x}$  under uniform illumination.

(Note 3) Measured at 50% of SE (Typ.)

RI is defined as follows:

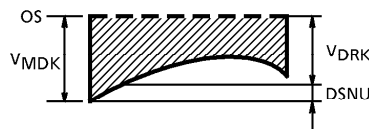
$$RI = \frac{\sum_{n=1}^{4999} |x_n - x_{n+1}|}{4999 \times \bar{x}} \times 100 (\%)$$

Where  $x_n$  and  $x_{n+1}$  are signal output of each pixel.  $\bar{x}$  is average of total signal output.

(Note 4) V<sub>SAT</sub> is defined as minimum saturation output voltage of all effective pixels.

(Note 5) Definition of SE :  $SE = \frac{V_{SAT}}{R} (l \times s)$

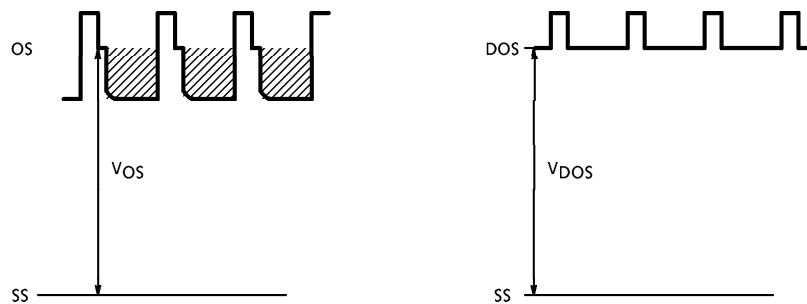
(Note 6)  $V_{DRK}$  is defined as average dark signal voltage of all effective pixels.  
 DSNU is defined as different voltage between  $V_{DRK}$  and  $V_{MDK}$  when  $V_{MDK}$  is maximum dark signal voltage.



(Note 7) Definition of DR :  $DR = \frac{V_{SAT}}{V_{DRK}}$

$V_{DRK}$  is proportional to  $t_{INT}$  (Integration Time).  
 So the shorter  $t_{INT}$  condition makes wider DR values.

(Note 8) DC signal output voltage and DC compensation output voltage are defined as follows:



(Note 9) PRUN(3) is defined as maximum voltage with next pixel, where measured 5% of SE (Typ.).

**OPERATING CONDITION**

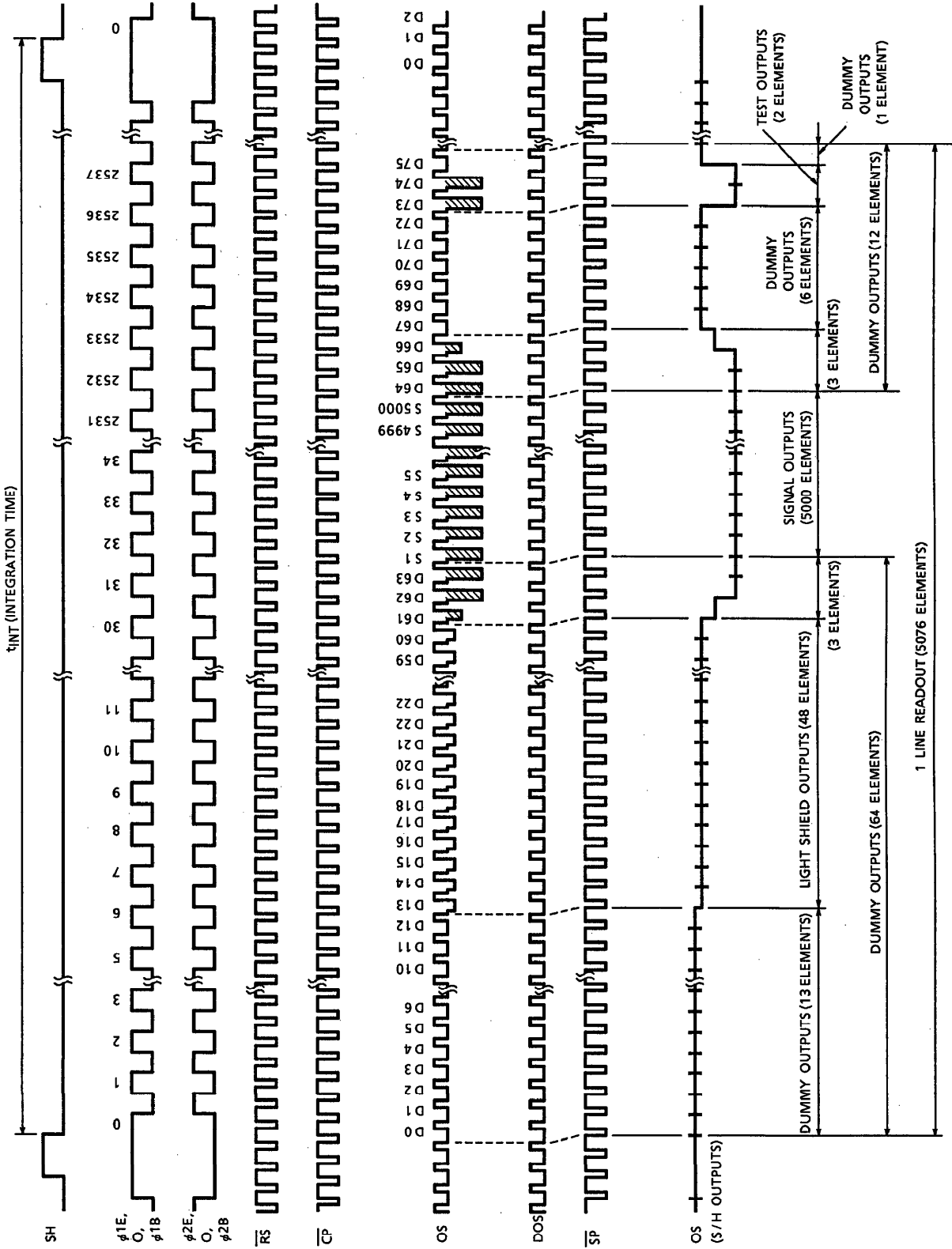
CHARACTERISTIC		SYMBOL	MIN.	TYP.	MAX.	UNIT
Clock Pulse Voltage	"H" Level	$V_{\phi 1E, O}$	4.5	5	5.5	V
	"L" Level	$V_{\phi 2E, O}$	0	—	0.5	
Final Stage Clock Voltage	"H" Level	$V_{\phi 1B}$	4.5	5	5.5	V
	"L" Level	$V_{\phi 2B}$	0	—	0.5	
Shift Pulse Voltage	"H" Level	$V_{SH}$	4.5	5	5.5	V
	"L" Level		0	—	0.5	
Reset Pulse Voltage	"H" Level	$V_{RS}$	4.5	5	5.5	V
	"L" Level		0	—	0.5	
Clamp Pulse Voltage	"H" Level	$V_{CP}$	4.5	5	5.5	V
	"L" Level		0	—	0.5	
Sample and Hold Pulse Voltage *	"H" Level	$V_{SP}$	4.5	5	5.5	V
	"L" Level		0	—	0.5	
Power Supply Voltage		$V_{OD}$	11.4	12.0	13.0	V

\* Supply "L" level to  $\overline{SP}$  terminal when sample-and-hold circuitry is not used.

**CLOCK CHARACTERISTICS (Ta = 25°C)**

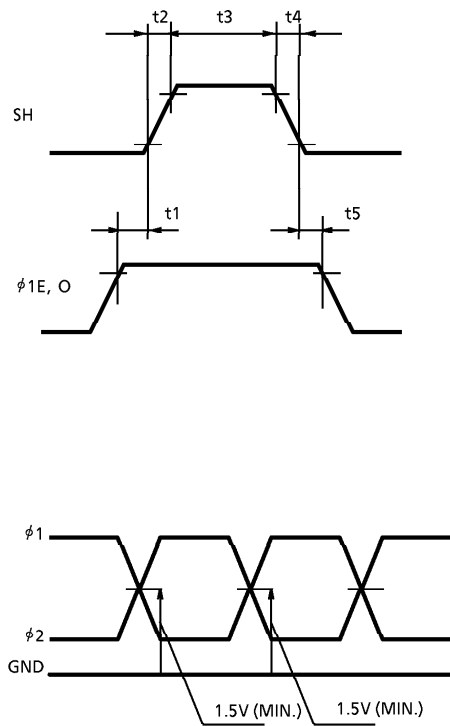
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Clock Pulse Frequency	$f_{\phi}$	—	0.5	6.0	MHz
Reset Pulse Frequency	$f_{\overline{RS}}$	—	1.0	12.0	MHz
Sample and Hold Pulse Frequency	$f_{\overline{SP}}$	—	1.0	2.0	MHz
Clock Capacitance	$C_{\phi E}$	—	350	450	pF
	$C_{\phi O}$	—	350	450	
Final Stage Clock Capacitance	$C_{\phi B}$	—	10	20	pF
Shift Gate Capacitance	$C_{SH}$	—	10	20	pF
Reset Gate Capacitance	$C_{\overline{RS}}$	—	10	20	pF
Clamp Gate Capacitance	$C_{\overline{CP}}$	—	10	20	pF
Sample and Hold Gate Capacitance	$C_{\overline{SP}}$	—	10	20	pF

TIMING CHART

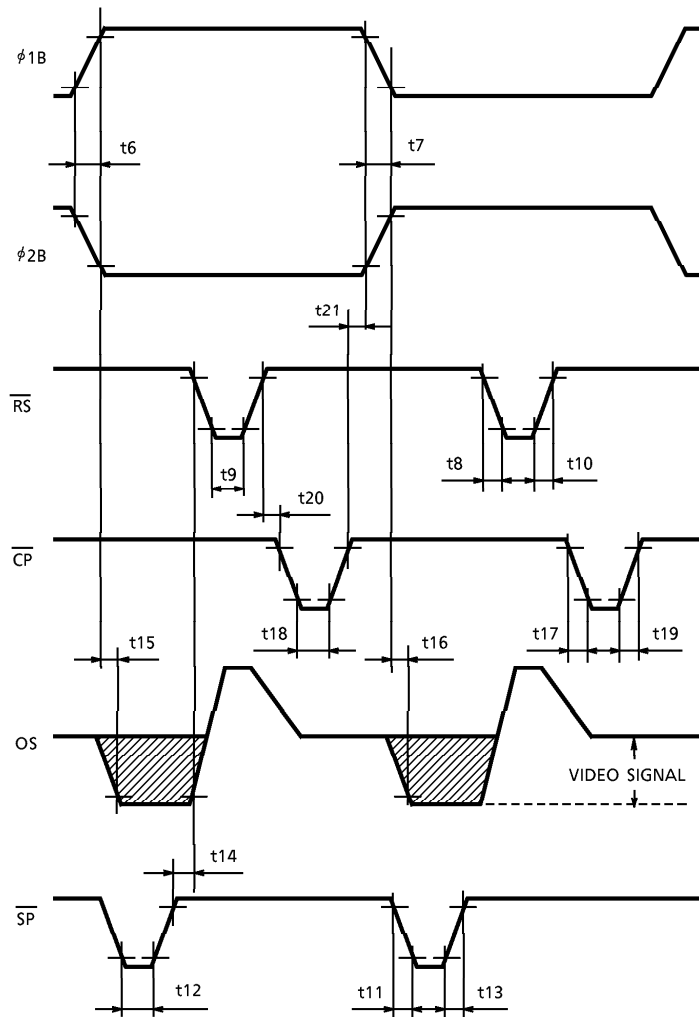


**TIMING REQUIREMENTS**

SH,  $\phi 1$  TIMING



$\phi 1, \phi 2, \overline{RS}, \overline{CP}, OS, \overline{SP}$  TIMING



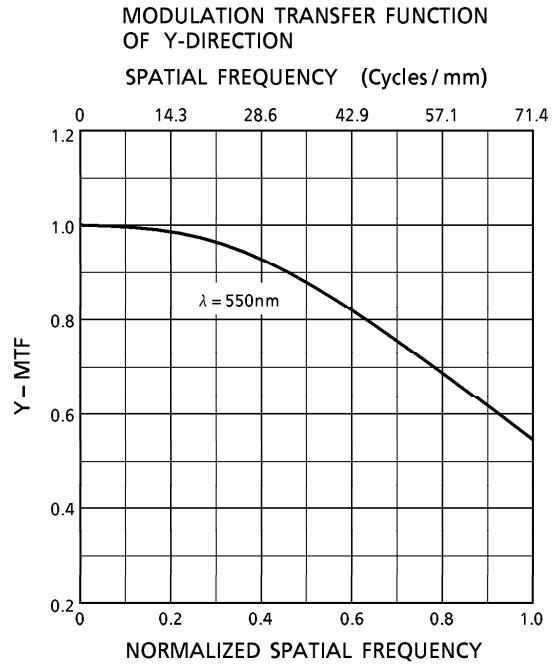
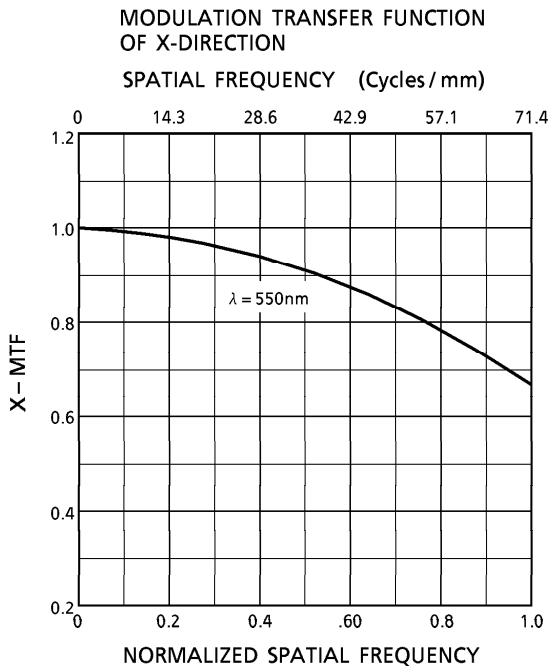
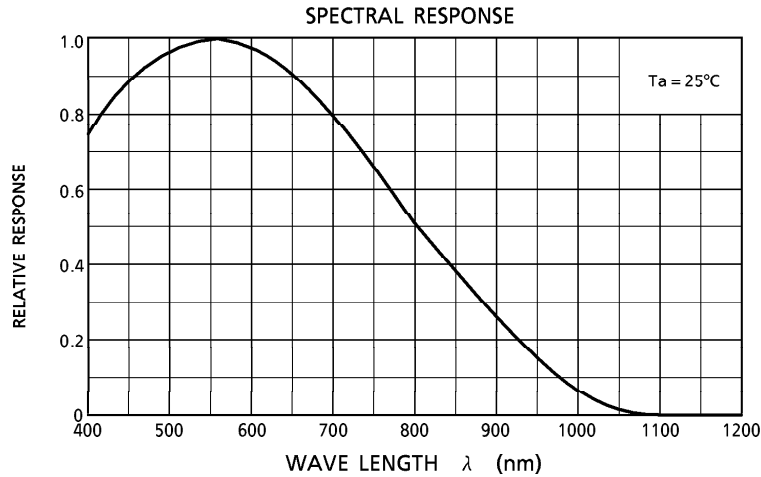
CHARACTERISTIC	SYMBOL	MIN.	TYP. (Note 10)	MAX.	UNIT
Pulse Timing of SH and $\phi$ 10, E	t1, t5	100	300	—	ns
SH Pulse Rise Time, Fall Time	t2, t4	0	50	—	ns
SH Pulse Width	t3	500	1000	—	ns
$\phi$ 1, $\phi$ 2 Pulse Rise Time, Fall Time	t6, t7	0	100	—	ns
$\overline{RS}$ Pulse Rise Time, Fall Time	t8, t10	0	20	—	ns
$\overline{RS}$ Pulse Width	t9	20	250	—	ns
$\overline{SP}$ Pulse Rise Time, Fall Time	t11, t13	0	20	—	ns
$\overline{SP}$ Pulse Width	t12	20	—	—	ns
Pulse Timing of $\overline{SP}$ and $\overline{RS}$	t14	0	50	—	ns
Video Data Delay Time (Note 11)	t15, t16	—	30	—	ns
$\overline{CP}$ Pulse Rise Time, Fall Time	t17, t19	0	20	—	ns
$\overline{CP}$ Pulse Width	t18	20	—	—	ns
Pulse Timing of $\overline{RS}$ and $\overline{CP}$	t20	0	—	—	ns
Pulse Timing of $\phi$ 1B, $\phi$ 2B and $\overline{CP}$	t21	0	—	—	ns

(Note 10) TYP. is the case of  $f_{RS} = 1.0\text{MHz}$

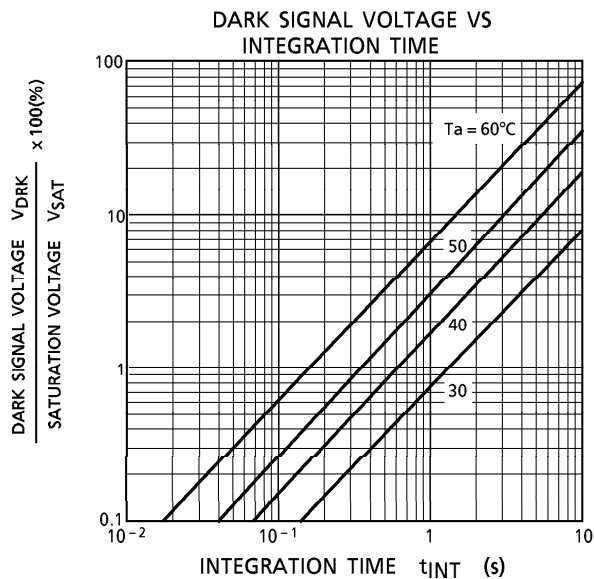
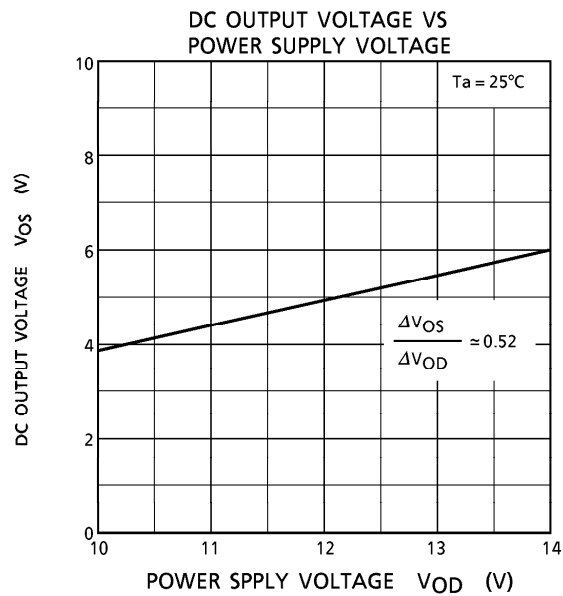
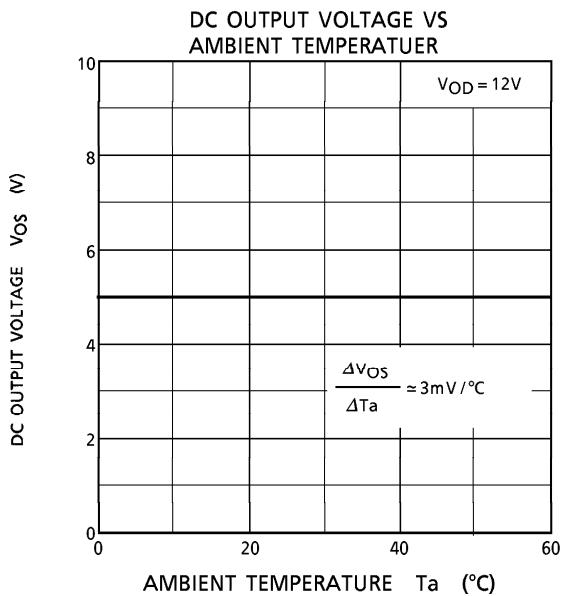
(Note 11) Load Resistance is  $100\text{k}\Omega$



TYPICAL PERFORMANCE CURVES



TYPICAL PERFORMANCE CURVES (Cont'd)



**CAUTION****1. Window Glass**

The dust and stain on the glass window of the package degrade optical performance of CCD sensor.

Keep the glass window clean by saturating a cotton swab in alcohol and lightly wiping the surface, and allow the glass to dry, by blowing with filtered dry N<sub>2</sub>.

Care should be taken to avoid mechanical or thermal shock because the glass window is easily damaged.

**2. Electrostatic Breakdown**

Store in shorting clip or in conductive foam to avoid electrostatic breakdown.

**3. Incident Light**

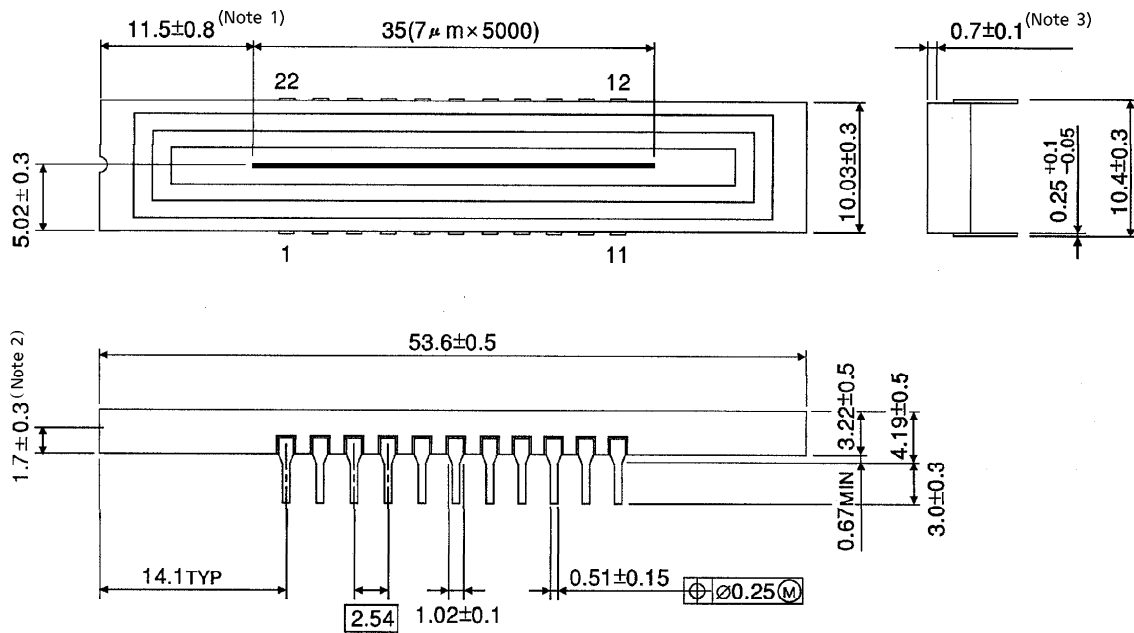
CCD sensor is sensitive to infrared light.

Note that infrared light component degrades resolution and PRNU of CCD sensor.

**PACKAGE OUTLINE**

WDIP22-C-400-2.54B (A)

Unit in mm



- (Note 1) No. 1 SENSOR ELEMENT (S1) TO EDGE OF PACKAGE.
- (Note 2) TOP OF CHIP TO BOTTOM OF PACKAGE.
- (Note 3) GLASS THICKNES (n = 1.5)

Weight : 5.4g (Typ.)